

BC807 series

45 V, 500 mA PNP general-purpose transistors

Rev. 8 — 1 July 2022

Product data sheet

1. General description

PNP general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package			NPN complement
	Nexperia	JEDEC	JEITA	
BC807	SOT23	TO-236AB	-	BC817
BC807-16				BC817-16
BC807-25				BC817-25
BC807-40				BC817-40

2. Features and benefits

- High current
- · Three current gain selections

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	-45	V
I _C	collector current	T _{amb} = 25 °C		-	-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	-1	Α
h _{FE}	DC current gain				·		
	BC807	V_{CE} = -1 V; I_{C} = -100 mA T_{amb} = 25 °C	[1]	100	-	600	
	BC807-16		[1]	100	-	250	
	BC807-25		[1]	160	-	400	
	BC807-40		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



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5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	E	emitter		B—
3	С	collector		, h
				E sym132
			1	

6. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
BC807	TO-236AB	Plastic surface-mounted package; 3 leads	SOT23			
BC807-16						
BC807-25						
BC807-40						

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC807	5D%
BC807-16	5A%
BC807-25	5B%
BC807-40	5C%

^{[1] % =} placeholder for manufacturing site code

2/13

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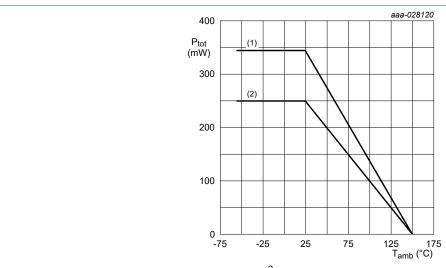
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C		-	-50	V
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C		-	-5	V
I _C	collector current	T _{amb} = 25 °C		-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	250	mW
			[3] [2]	-	345	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

Fig. 1. Power derating curves for SOT23

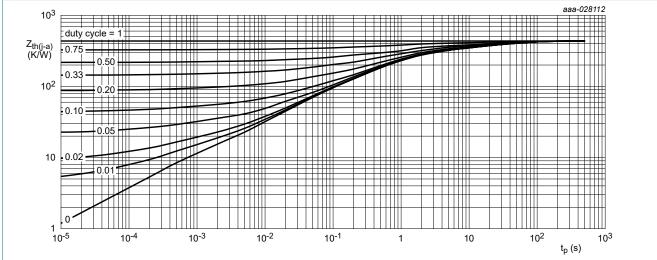
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9. Thermal characteristics

Table 7. Thermal characteristics

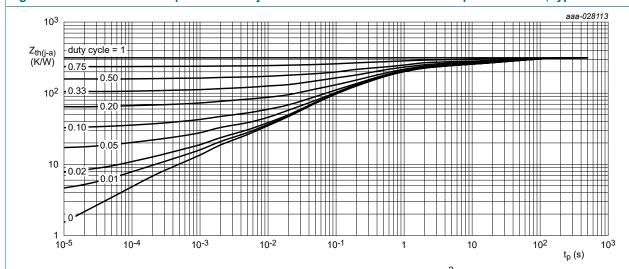
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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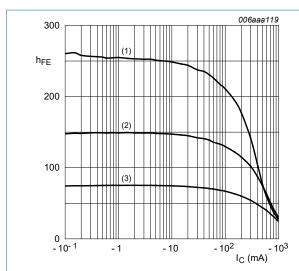
10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \ \mu\text{A}; \ I_E = 0 \ \text{A}; \ T_{amb} = 25 \ ^{\circ}\text{C}$		-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -10 mA; I _E = 0 A; T _{amb} = 25 °C		-45	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	$I_E = -100 \ \mu A; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$		-5	-	-	V
I _{CBO}	collector-base	V _{CB} = -20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	cut-off current	$V_{CB} = -20 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain			'	'	'	
	BC807	V _{CE} = -1 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	100	-	600	
	BC807-16		[1]	100	-	250	
	BC807-25		[1]	160	-	400	
	BC807-40		[1]	250	-	600	
h _{FE}	DC current gain	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	-700	mV
V_{BE}	base-emitter voltage	V _{CE} = -1 V; I _C = -500 mA; T _{amb} = 25 °C	[1] [2]	-	-	-1.2	V
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz; T _{amb} = 25 °C		80	-	-	MHz
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = I_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	5	-	pF

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$

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$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 4. BC807-16: DC current gain as a function of collector current; typical values

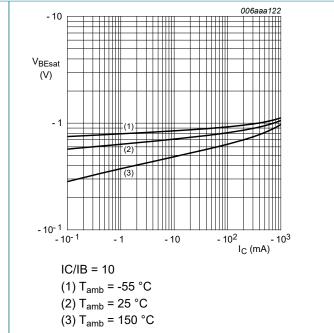
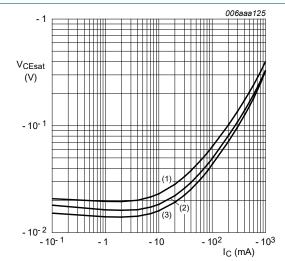


Fig. 5. BC807-16: Base-emitter saturation voltage as a function of collector current; typical values



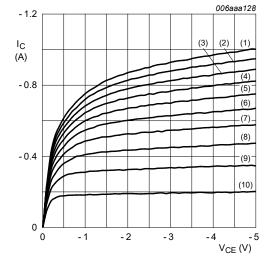
$$IC/IB = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 6. BC807-16: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = -16.0 \text{ mA}$$

(2)
$$I_B = -14.4 \text{ mA}$$

$$(3) I_B = -12.8 \text{ mA}$$

$$(4) I_B = -11.2 \text{ mA}$$

$$(5) I_B = -9.6 \text{ mA}$$

(6)
$$I_B = -8.0 \text{ mA}$$

$$(7) I_B = -6.4 \text{ mA}$$

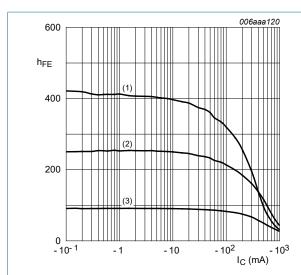
(8)
$$I_B = -4.8 \text{ mA}$$

(9)
$$I_B = -3.2 \text{ mA}$$

$$(10) I_B = -1.6 \text{ mA}$$

Fig. 7. BC807-16: Collector current as a function of collector-emitter voltage; typical values

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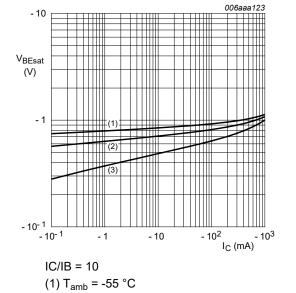
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

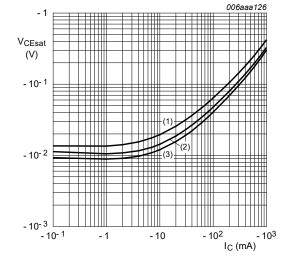
Fig. 8. BC807-25: DC current gain as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC807-25: Base-emitter saturation voltage as a function of collector current; typical values



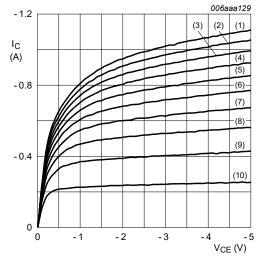
$$IC/IB = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig. 10. BC807-25: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -13.0 \text{ mA}$$

(2)
$$I_B = -11.7 \text{ mA}$$

(3)
$$I_B = -10.4 \text{ mA}$$

(4)
$$I_B = -9.1 \text{ mA}$$

$$(5) I_B = -7.8 \text{ mA}$$

(6)
$$I_B = -6.5 \text{ mA}$$

$$(7) I_B = -5.2 \text{ mA}$$

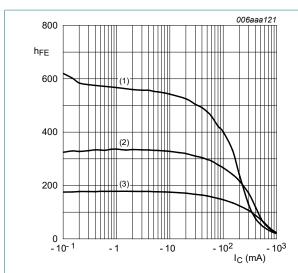
(8)
$$I_B = -3.9 \text{ mA}$$

(9)
$$I_B = -2.6 \text{ mA}$$

$$(10) I_B = -1.3 \text{ mA}$$

Fig. 11. BC807-25: Collector current as a function of collector-emitter voltage; typical values

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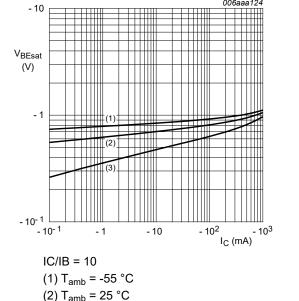
$$V_{CE} = -1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

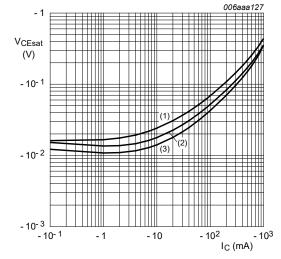
Fig. 12. BC807-40: DC current gain as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

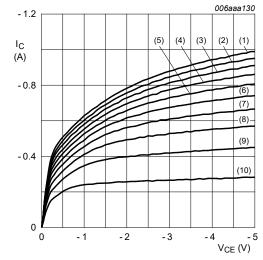
Fig. 13. BC807-40: Base-emitter saturation voltage as a function of collector current; typical values



$$IC/IB = 10$$

(2)
$$T_{amb}$$
 = 25 °C

Fig. 14. BC807-40: Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_B = -12.0 \text{ mA}$$

(2)
$$I_B = -10.8 \text{ mA}$$

(3)
$$I_B = -9.6 \text{ mA}$$

$$(4) I_B = -8.4 \text{ mA}$$

$$(5) I_B = -7.2 \text{ mA}$$

(6)
$$I_B = -6.0 \text{ mA}$$

$$(7) I_B = -4.8 \text{ mA}$$

(8)
$$I_B = -3.6 \text{ mA}$$

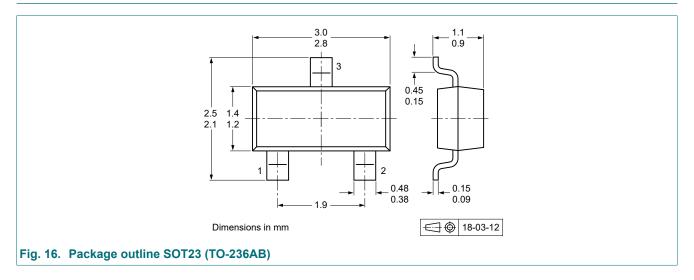
(9)
$$I_B = -2.4 \text{ mA}$$

$$(10) I_B = -1.2 mA$$

Fig. 15. BC807-40: Collector current as a function of collector-emitter voltage; typical values

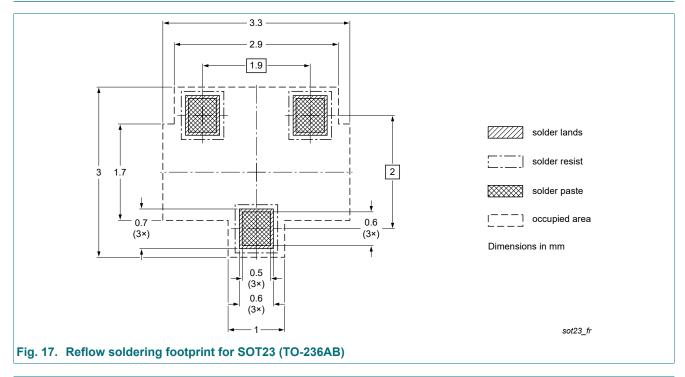
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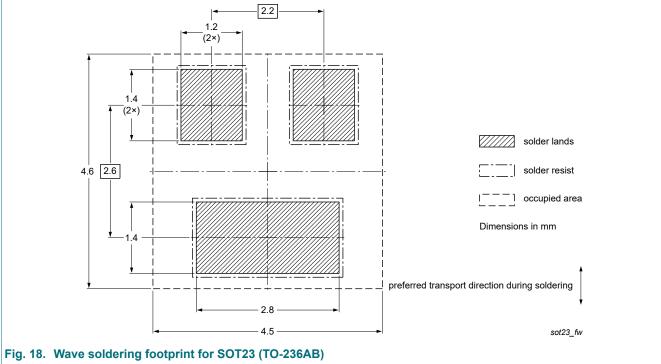
11. Package outline



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12. Soldering





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13. Revision history

Table 9. Revision history

Table 3. INEVISION MISION				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC807_SER v.8	20220701	Product data sheet	-	BC807_SER v.7
Modifications:		hanged to non-automot (-Q) product alternative(refer to nexperia.com for
BC807_SER v.7	20180615	Product data sheet	-	BC807_BC807W_BC327 v.6
BC807_BC807W_BC327 v.6	20091117	Product data sheet	-	BC807_BC807W_BC327 v.5
BC807_BC807W_BC327 v.5	20050221	Product data sheet	CPCN200302007F CPCN200405006F	BC807 v.4 BC807W v.3 BC327 v.3
BC807 v.4	20040116	Product Specification	-	BC807 v.3
BC807W v.3	19990518	Product Specification	-	BC807W_808W_CNV v.2
BC327 v.3	19990415	Product Specification	-	BC327 v.2

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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